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**PALM INTRANET**

## Inventor Name Search Result

Your Search was:

Last Name = ZHANG

First Name = HONGYONG

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<a href="#">07606189</a>	Not Issued	166	10/31/1990	METHOD OF MANUFACTURING GATE INSULATED FIELD EFFECT TRANSISTORS	ZHANG, HONGYONG
<a href="#">07650166</a>	Not Issued	166	02/04/1991	METHOD OF FORMING AN OXIDE FILM	ZHANG, HONGYONG
<a href="#">07673417</a>	Not Issued	166	03/22/1991	METHOD OF MANUFACTURING GATE INSULATED FIELD EFFECT TRANSISTORS	ZHANG, HONGYONG
<a href="#">07704103</a>	Not Issued	166	05/22/1991	THIN-FILM TRANSISTOR	ZHANG, HONGYONG
<a href="#">07707092</a>	Not Issued	166	05/29/1991	METHOD FOR FABRICATING THIN-FILM TRANSISTOR	ZHANG, HONGYONG
<a href="#">07729999</a>	<a href="#">5254208</a>	150	07/15/1991	METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<a href="#">07761648</a>	<a href="#">5236850</a>	150	09/18/1991	METHOD OF MANUFACTURING A SEMICONDUCTOR FILM AND A SEMICONDUCTOR DEVICE BY SPUTTERING IN A HYDROGEN ATMOSPHERE AND CRYSTALLIZING	ZHANG, HONGYONG
<a href="#">07774852</a>	<a href="#">5210050</a>	150	10/11/1991	METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE COMPRISING A SEMICONDUCTOR FILM	ZHANG, HONGYONG
<a href="#">07810422</a>	<a href="#">5320984</a>	150	12/20/1991	METHOD FOR FORMING A SEMICONDUCTOR FILM BY SPUTTER DEPOSITION IN A HYDROGEN ATMOSPHERE	ZHANG, HONGYONG

<u>07852517</u>	Not Issued	166	03/17/1992	SEMICONDUCTOR MATERIAL AND METHOD FOR FORMING THE SAME AND THIN FILM TRANSISTOR	ZHANG, HONGYONG
<u>07853690</u>	5313076	150	03/17/1992	A THIN FILM TRANSISTOR AND SEMICONDUCTOR DEVICE INCLUDING A LASER CRYSTALLIZED SEMICONDUCTOR	ZHANG, HONGYONG
<u>07886817</u>	Not Issued	166	05/22/1992	METHOD OF ANNEALING A SEMICONDUCTOR	ZHANG, HONGYONG
<u>07895029</u>	Not Issued	166	06/08/1992	THIN FILM TRANSISTOR AND ELECTRO-OPTICAL DEVICE USING THE SAME	ZHANG, HONGYONG
<u>07922759</u>	Not Issued	166	07/31/1992	SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<u>07933810</u>	5308998	150	08/24/1992	INSULATED GATE FIELD EFFECT SEMICONDUCTOR DEVICES HAVING A LDD REGION AND AN ANODIC OXIDE FILM OF A GATE ELECTRODE	ZHANG, HONGYONG
<u>07956860</u>	Not Issued	166	10/05/1992	METHOD FOR FORMING A SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<u>07966607</u>	6586346	150	10/26/1992	METHOD OF FORMING AN OXIDE FILM	ZHANG, HONGYONG
<u>07971237</u>	5424244	150	11/04/1992	PROCESS FOR LASER PROCESSING AND APPARATUS FOR USE IN THE SAME	ZHANG, HONGYONG
<u>07998729</u>	Not Issued	166	12/30/1992	METHOD FOR FORMING A FIELD-EFFECT TRANSISTOR INCLUDING ANODIC OXIDATION OF THE GATE	ZHANG, HONGYONG
<u>08001544</u>	Not Issued	166	01/06/1993	SEMICONDUCTOR DEVICE AND METHOD FOR MANUFACTURING THE SAME	ZHANG, HONGYONG
<u>08014455</u>	5485019	150	02/03/1993	SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG
<u>08019880</u>	5894151	150	02/19/1993	SEMICONDUCTOR DEVICE HAVING REDUCED LEAKAGE CURRENT	ZHANG, HONGYONG
<u>08025440</u>	Not	166	02/24/1993	SEMICONDUCTOR DEVICE	ZHANG,

	Issued			AND METHOD FOR FORMING THE SAME	HONGYONG
<u>08037162</u>	<u>5468987</u>	150	03/25/1993	SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG
<u>08043782</u>	<u>5545571</u>	150	04/06/1993	METHOD OF MAKING TFT WITH ANODIC OXIDATION PROCESS USING POSITIVE AND NEGATIVE VOLTAGES	ZHANG, HONGYONG
<u>08044883</u>	<u>5313075</u>	150	04/09/1993	THIN-FILM TRANSISTOR	ZHANG, HONGYONG
<u>08053227</u>	<u>5576225</u>	150	04/28/1993	METHOD OF FORMING ELECTRIC CIRCUIT USING ANODIC OXIDATION	ZHANG, HONGYONG
<u>08073689</u>	<u>5716857</u>	150	06/09/1993	METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<u>08081696</u>	Not Issued	166	06/25/1993	LASER PROCESS	ZHANG, HONGYONG
<u>08085931</u>	Not Issued	166	07/06/1993	SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG
<u>08089650</u>	<u>6458200</u>	150	07/12/1993	METHOD FOR FABRICATING THIN-FILM TRANSISTOR	ZHANG, HONGYONG
<u>08095172</u>	<u>6271066</u>	150	07/23/1993	SEMICONDUCTOR MATERIAL AND METHOD FOR FORMING THE SAME AND THIN FILM TRANSISTOR	ZHANG, HONGYONG
<u>08104614</u>	<u>5352291</u>	150	08/11/1993	METHOD OF ANNEALING A SEMICONDUCTOR	ZHANG, HONGYONG
<u>08111522</u>	Not Issued	166	08/25/1993	SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG
<u>08131958</u>	Not Issued	166	10/08/1993	SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG
<u>08138066</u>	<u>5533040</u>	150	10/20/1993	LASER PROCESSING METHOD	ZHANG, HONGYONG
<u>08160908</u>	<u>5403772</u>	150	12/03/1993	METHOD FOR MANUFACTURING SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<u>08183800</u>	<u>5962869</u>	150	01/21/1994	SEMICONDUCTOR MATERIAL AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG

				AND THIN FILM TRANSISTOR	
<u>08189658</u>	Not Issued	166	02/01/1994	PROCESS FOR FABRICATING SEMICONDUCTOR AND PROCESS FOR FABRICATING SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<u>08190228</u>	Not Issued	166	02/01/1994	SEMICONDUCTOR DEVICE AND METHOD FOR FORMING THE SAME	ZHANG, HONGYONG
<u>08190846</u>	<u>5561081</u>	150	02/03/1994	METHOD OF FORMING A SEMICONDUCTOR DEVICE BY ACTIVATING REGIONS WITH A LASER LIGHT	ZHANG, HONGYONG
<u>08195713</u>	Not Issued	166	02/14/1994	SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING THE SAME	ZHANG, HONGYONG
<u>08195714</u>	Not Issued	166	02/14/1994	SEMICONDUCTOR AND PROCESS FOR FABRICATING THE SAME	ZHANG, HONGYONG
<u>08196856</u>	<u>5639698</u>	150	02/15/1994	SEMICONDUCTOR, SEMICONDUCTOR DEVICE, AND METHOD FOR FABRICATING THE SAME	ZHANG, HONGYONG
<u>08199956</u>	Not Issued	166	02/22/1994	PROCESS FOR FABRICATING ELECTRONIC CIRCUITS	ZHANG, HONGYONG
<u>08205300</u>	Not Issued	166	03/03/1994	SEMICONDUCTOR INTEGRATED CIRCUIT, SEMICONDUCTOR DEVICE, TRANSISTOR, AND PROCESS FOR FABRICATING THE SAME	ZHANG, HONGYONG
<u>08207124</u>	<u>5569936</u>	150	03/08/1994	SEMICONDUCTOR DEVICE EMPLOYING CRYSTALLIZATION CATALYST	ZHANG, HONGYONG
<u>08207126</u>	<u>5426064</u>	150	03/08/1994	METHOD OF FABRICATING A SEMICONDUCTOR DEVICE	ZHANG, HONGYONG
<u>08207173</u>	<u>5624851</u>	150	03/08/1994	PROCESS OF FABRICATING A SEMICONDUCTOR DEVICE IN WHICH ONE PORTION OF AN AMORPHOUS SILICON FILM IS THERMALLY CRYSTALLIZED AND ANOTHER PORTION IS LASER CRYSTALLIZED	ZHANG, HONGYONG
<u>08207182</u>	Not	166	03/08/1994	TRANSISTOR AND PROCESS	ZHANG,

	Issued		FOR FABRICATING THE SAME	HONGYONG
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## Inventor Name Search Result

Your Search was:

Last Name = MIWA

First Name = HIROKAZU

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<a href="#">08631615</a>	<a href="#">5796379</a>	150	04/10/1996	DIGITAL DATA LINE DRIVER ADAPTED TO REALIZE MULTIGRAY-SCALE DISPLAY OF HIGH QUALITY	MIWA, HIROKAZU
<a href="#">08710374</a>	<a href="#">5999158</a>	150	09/16/1996	DISPLAY DEVICE, DRIVE CIRCUIT FOR THE DISPLAY DEVICE, AND METHOD OF DRIVING THE DISPLAY DEVICE	MIWA, HIROKAZU
<a href="#">09288741</a>	<a href="#">6806862</a>	150	04/08/1999	LIQUID CRYSTAL DISPLAY DEVICE	MIWA, HIROKAZU
<a href="#">10023344</a>	Not Issued	41	12/17/2001	Liquid crystal display	MIWA, HIROKAZU
<a href="#">10386156</a>	Not Issued	71	03/11/2003	Simulation method	MIWA, HIROKAZU
<a href="#">10689324</a>	Not Issued	41	10/20/2003	Liquid crystal display device	MIWA, HIROKAZU
<a href="#">10949300</a>	Not Issued	30	09/27/2004	Microcontroller	MIWA, HIROKAZU

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